

PROBLEM SET #11

Issued: Tuesday, Apr. 17, 2012

Due: Tuesday, Apr. 24, 2012, 6:00 p.m. in the EE 140 homework box in 240 Cory

1. For the two-stage BiCMOS op amp shown in Fig. PS11.1, assume $V_{DD} = 1.2V$, $C_L = 5pF$, $I_{REF} = 20\mu A$, and $(W/L)_7 = (W/L)_8$. Also, assume the output voltage V_{out} is biased to 0V DC. The table below provides transistor parameter values. If necessary (and it might not be), determine any needed MOS capacitor values assuming lambda design rules.

MOS				
$\mu_p=250cm^2/V\cdot s$	$V_{tp}=-0.5V$	$L_{drawn}=1\mu m$	$t_{ox}=150\text{\AA}$	$\lambda=0.1V^{1/2}$
$\psi_0=0.7V$	$n=0.5$	$C_{j0}=0.3fF/\mu m^2$	$C_{jsw0}=2.2fF/\mu m$	$C_{ol}=0.18fF/\mu m^2$
BJT				
$\beta_F=100$	$V_A=50V$	$V_T=26mV$	$\tau_F=20ns$	$I_S=10^{-14}A$
$C_{je0}=0.5pF$	$C_{\mu 0}=2pF$	$C_{cs0}=0.5pF$	$\psi_{os}=\psi_{oc}=0.6V$	$n_c=n_e=0.5$
$V_{CE(sat)}=0.2V$				

Design values for the compensation capacitor C_C and the sizes of each MOS transistor to satisfy the following specifications:

- i. Unity-gain bandwidth $\geq 1MHz$
- ii. Phase margin $\geq 60^\circ$ for unity-gain feedback
- iii. Output swing $\pm 1V$
- iv. Open-loop voltage gain $\geq 80dB$

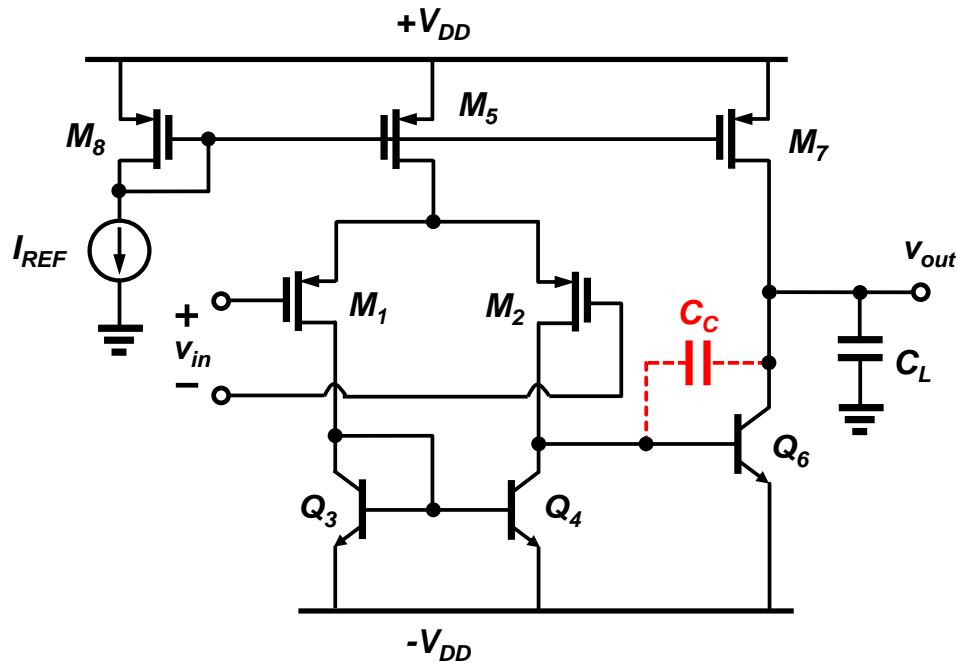


Fig. PS11.1